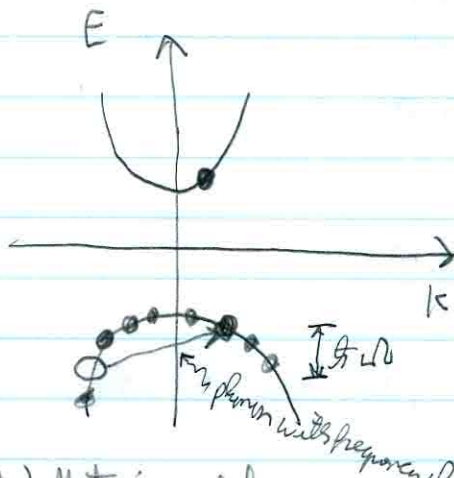
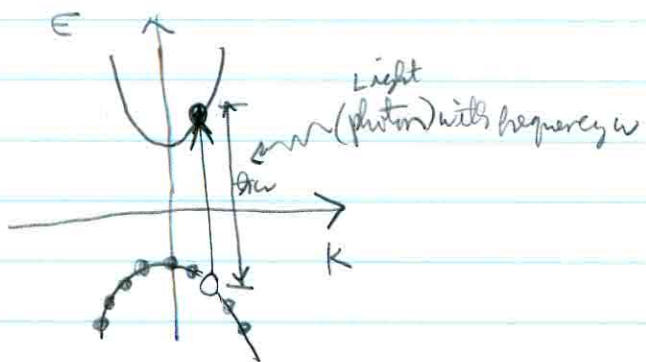


Lecture 7

Quasiparticles: Electrons, holes, and excitons



(a) A photon is absorbed by a semiconductor and an electron-hole pair is created

(b) Motion of a hole:

An electron may scatter into this hole state, leaving a hole at its original ^{state}. This is equivalent to a hole moving with opposite \vec{K} .

A "hole" is as good a particle as a real electron. The only distinction is:

	Electron	hole
Charge	$- e $	$+ e $
Momentum	$+\hbar\vec{K}$	$-\hbar\vec{K}$
Mass	m_e^*	m_h^*

A good analogy is a bubble moving in a liquid

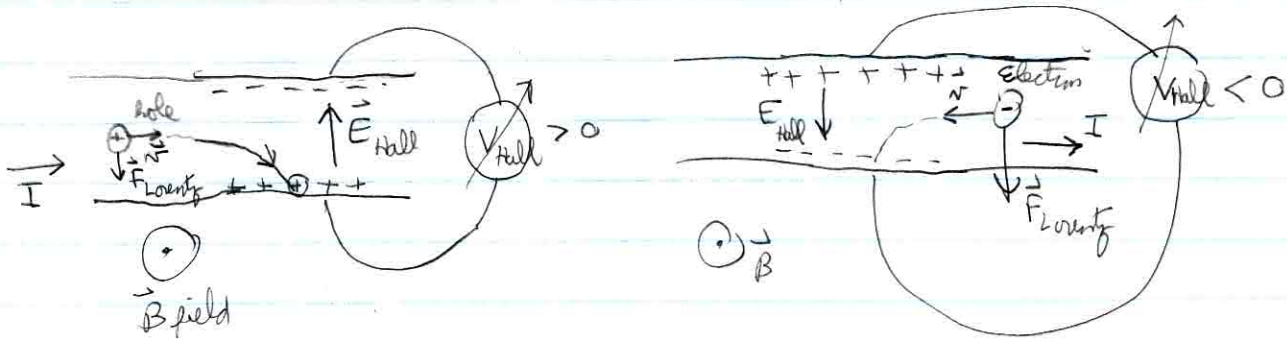


\vec{P}

It is much more convenient to think of the bubble going up rather than thinking of the liquid "going down".

7

How to determine the sign of the charge carriers? Hall Voltage!

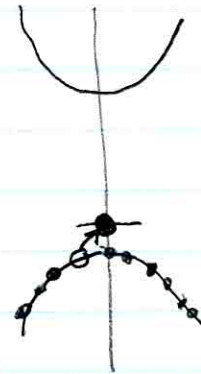
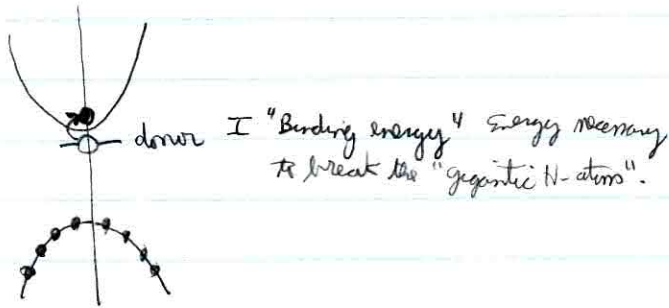


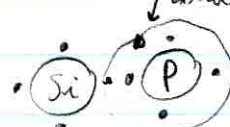
Lorentz Force

$$\vec{F} = q \frac{\vec{v}}{c} \times \vec{B}$$

The sign of the Hall Voltage depends on the sign of the charge carriers!

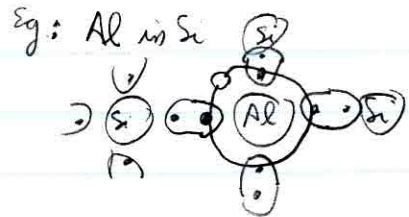
How to get charge carriers in a semiconductor?



Dope with a Donor: Impurity atom has larger valence than lattice atom.
 Eg. P in Si:  Extra electron! Lots like a giantic H-atom is stable for an atom

Negative charge carrier!

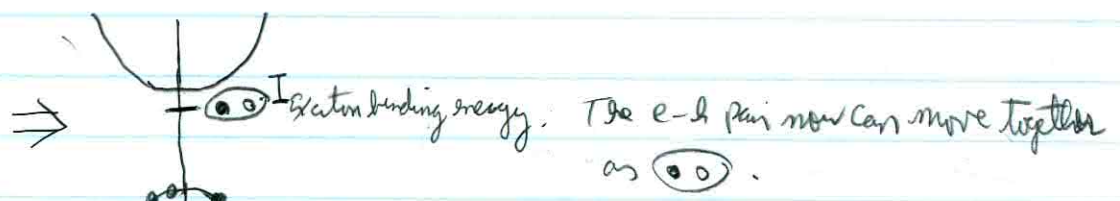
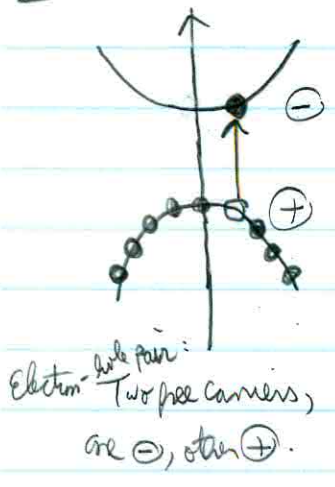
Dope with acceptor: Impurity has smaller valence than lattice atoms



Positive charge carriers!

Excitons

Wannier exciton: (For delocalized electrons and holes).



They attract each other and bind forming a "large H-atom": exciton.

Exciton: Atom formed by an electron orbiting around a hole:



$$\vec{r} = \vec{r}_e - \vec{r}_h$$

$$\vec{R} = \frac{\vec{r}_e + \vec{r}_h}{2}$$

$$H = \frac{\vec{p}^2}{2(m_h^* + m_e^*)} + \frac{\vec{p}^2}{2m_{\text{reduced}}} - \frac{e^2}{\epsilon |\vec{r}|}$$

with $m_{\text{reduced}} = \frac{m_h^* m_e^*}{m_h^* + m_e^*}$

Try $\psi(\vec{R}, \vec{r}) = \frac{e^{i\vec{k} \cdot \vec{R}}}{\sqrt{V}} \frac{e^{-\frac{r}{a^*}}}{\sqrt{\pi a^{*3}}} \left(\frac{|\uparrow\downarrow\rangle - |\downarrow\uparrow\rangle}{\sqrt{2}} \right)$ (Exciton ground state!)

Excited states for $m > 1$; generally: (ψ_m can be Triplet or singlet for $m > 1$, but for $m=1$ can only be singlet!)

$$H \psi_m = \left[\frac{\hbar^2 k^2}{2(m_h^* + m_e^*)} - \frac{Ry^1}{m^2} \right] \psi_m$$

$$Ry^1 = \frac{1}{2} \frac{e^2}{\epsilon a^*}, \quad a^* = \frac{\epsilon \hbar^2}{e^2 m_{\text{reduced}}}$$

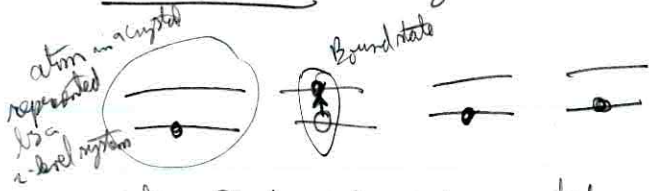
(Just make $e^2 \rightarrow \frac{e^2}{\epsilon}$ in Atom formulas!)

	ϵ	Exciton binding energy	a^*
Si	11.4	12 meV	50 Å
GaN	13.1	4 meV	150 Å

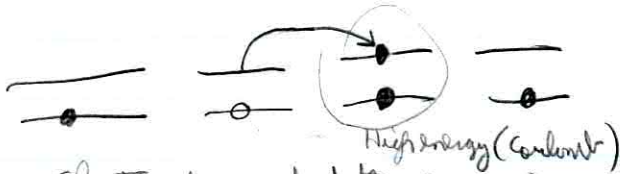
②

Frenkel's exciton (Localized electron and holes)

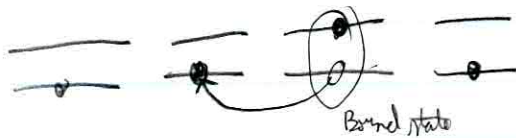
Exciton is so tightly bound that it sits in the same lattice site.



Localized Electron-hole pair is excited



Electron hops, but the energy of one of the atoms now too high



To relieve this Coulomb energy, electron moves to nearest neighbour -
 ⇒ As a result, exciton can move across crystal.

The concept of a quasiparticle

The fundamental ^{electron} Hamiltonian: (assuming lattice atoms are frozen)

$$H = \sum_i \left[\frac{\vec{p}_i^2}{2m} + U(\vec{r}_i) \right] + \sum_{i < j} \frac{e^2}{|\vec{r}_i - \vec{r}_j|}$$

Interesting! Why can I neglect?

The quasiparticle concept: I can ignore the Coulomb repulsion between electrons provided I think of electrons and holes not as single stationary states, but rather as a wavepacket of Bloch states.
 ⇒ Not an eigenstate, finite lifetime τ .

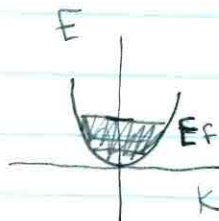
- e-e interaction {
- ① may affect m_e^* , m_h^* and gives $\epsilon > 1$ (screening).
 - ② electron and hole excitations get a "lifetime" τ .

Here is a particle ⇒ (Hole + dust around it) is a quasiparticle.

Isotropic Fermi gas at $T=0$

$\beta = k_B T$
 $f(\epsilon) = \frac{1}{e^{\beta(\epsilon - \mu)} + 1}, \mu(T=0) \equiv \epsilon_F$

When $T=0 \Rightarrow f(\epsilon) = \theta(\epsilon_F - \epsilon)$.



$N = \int_0^\infty d\epsilon D(\epsilon) f(\epsilon) = \int_0^{\epsilon_F} d\epsilon D(\epsilon)$

$D(\epsilon) d\epsilon = \frac{4\pi k^2 dk}{(2\pi)^3} = \frac{V}{\pi^2} \frac{k^2}{\frac{d\epsilon}{dk}} d\epsilon = \frac{V}{\pi^2} \frac{k^3}{m} d\epsilon = \underbrace{\left(\frac{V}{\pi^2} \frac{m}{\hbar^2} \sqrt{\frac{2m\epsilon}{\hbar^2}} \right)}_{D(\epsilon)} d\epsilon$

$N = \frac{V}{\pi^2} \frac{m}{\hbar^2} \sqrt{\frac{2m}{\hbar^2}} \int_0^{\epsilon_F} d\epsilon \sqrt{\epsilon} = \frac{V \sqrt{2}}{\pi^2} \frac{m^{3/2}}{\hbar^3} \frac{2}{3} \epsilon_F^{3/2} \Rightarrow \left(\frac{N}{V} \right) = \frac{2^{3/2}}{3\pi^2} \frac{m^{3/2}}{\hbar^3} \epsilon_F^{3/2}$

$\epsilon_F = \left(\frac{3\pi^2}{2} \frac{\hbar^3}{m^{3/2}} \right)^{2/3} \left(\frac{N}{V} \right)^{2/3} = \frac{\hbar^2}{2m} \underbrace{\left(3\pi^2 \right)^{2/3}}_{K_F^2} m^{2/3} \left(m \equiv \frac{N}{V} \text{ is density} \right)$

$\epsilon_F = \frac{\hbar^2}{2m} K_F^2 = \frac{\hbar^2}{2m} \left(3\pi^2 n \right)^{2/3} \propto m^{2/3}$

$n \sim 10^{23} \text{ cm}^{-3} \Rightarrow \epsilon_F \sim 10 \text{ eV}$. Also, $\epsilon_F = k_B T_F \Rightarrow T_F \sim 10^4 - 10^5 \text{ K}!$

introduce at 4 Metals are "very quantum" even at Room Temp.

Pressure and Compressibility of the Fermi gas

$P = - \frac{\partial U}{\partial V}; U = \int_0^{\epsilon_F} d\epsilon \epsilon D(\epsilon) = \frac{V \sqrt{2}}{\pi^2} \frac{m^{3/2}}{\hbar^3} \int_0^{\epsilon_F} d\epsilon \epsilon^{3/2} = \frac{\sqrt{2}}{\pi^2} \frac{m^{3/2}}{\hbar^3} \frac{2}{5} \epsilon_F^{5/2} = N \frac{3}{5} \epsilon_F$

$U = \frac{3/2}{3\pi^2} \frac{m^{3/2}}{\hbar^3} \frac{2}{5} \left(\frac{3\pi^2}{2} \frac{\hbar^3}{m^{3/2}} \right)^{5/3} \frac{N^{5/3}}{V^{5/3}} V = \frac{3}{5} \left(\frac{3\pi^2}{2} \frac{\hbar^3}{m^{3/2}} \right)^{2/3} \frac{N^{5/3}}{V^{2/3}} = \frac{A}{V^{2/3}}$

④

$$P = -\frac{\partial U}{\partial V} = \frac{2}{3} \frac{U}{V} = \frac{2}{3} \frac{\frac{3}{5} N E_F}{V} = \frac{2}{5} n E_F \quad (\text{Quite High Pressure!})$$

Bulk Compressibility: $B = -V \frac{\partial P}{\partial V} = \frac{5}{3} P = \frac{5}{3} \frac{2}{5} n E_F = \frac{2}{3} n E_F //$

Pressure needed to change volume by 1%: $\Delta P = B \frac{\Delta V}{V} = 10^{-2} B = 10^{-2} \times \frac{2}{3} \times 10^{23} \text{ cm}^{-3} \times 10 \text{ eV} \sim 10^4 \text{ atm!}$

Fermi gas of a metal is hard to compress!

Why ^{metal} doesn't expand indefinitely?

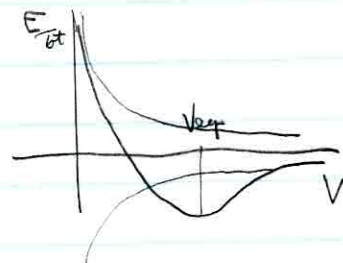
Consider e.g. electrostatic energy: $E_{\text{attraction}} = \int d^3r \left(-\frac{eN}{V} \right) \sum_{i=1}^{N_A} \frac{Ne}{|\vec{r} - \vec{R}_i|}$

$\underbrace{\hspace{10em}}_{\text{Electron } (N_A n = N)}$
 $= -\frac{(Ne)^2}{V} \int_0^R \frac{4\pi r^2 dr}{r} = -\frac{(Ne)^2}{V} 4\pi \frac{R^2}{2}$

$= -\frac{(Ne)^2}{V} \left(\frac{4\pi R^3}{3} \right)^{\frac{2}{3}} \frac{2\pi}{\left(\frac{4\pi}{3} \right)^{\frac{2}{3}}} = -\left(\frac{2^{\frac{3}{2}} \pi^{\frac{3}{2}}}{3} \right)^{\frac{2}{3}} \frac{(Ne)^2}{V^{\frac{1}{3}}}$

$$E_{\text{attrac}} = -\frac{B}{V^{\frac{1}{3}}}$$

$$E_{\text{Total}} = \frac{A}{V^{\frac{2}{3}}} - \frac{B}{V^{\frac{1}{3}}}$$



$$\left. \frac{dE_{\text{Total}}}{dV} \right|_{V=V_{\text{eq}}} = 0 \Rightarrow V_{\text{equilibrium}}$$

⇒ Complete analysis of cohesiveness of metals will be done in P507B.